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February 2016



FOD3120 High Noise Immunity, 2.5 A Output Current, Gate Drive Optocoupler

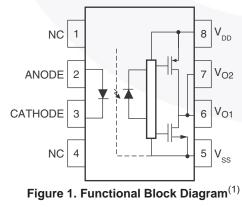
Features

- High Noise Immunity Characterized by 35 kV/µs Minimum Common Mode Rejection
- 2.5 A Peak Output Current Driving Capability for Most 1200 V/20 A IGBT
- Use of P-channel MOSFETs at Output Stage Enables Output Voltage Swing Close to The Supply Rail
- Wide Supply Voltage Range from 15 V to 30 V
- Fast Switching Speed
 - 400 ns max. Propagation Delay
 - 100 ns max. Pulse Width Distortion
- Under Voltage LockOut (UVLO) with Hysteresis
- Extended Industrial Temperate Range, -40°C to 100°C Temperature Range
- Safety and Regulatory Approved
 UL1577, 5000 V_{RMS} for 1 min.
 - DIN EN/IEC60747-5-5
- R_{DS(ON)} of 1 Ω (typ.) Offers Lower Power Dissipation
- >8.0 mm Clearance and Creepage Distance (Option 'T' or 'TS')
- 1,414 V Peak Working Insulation Voltage (VIORM)

Applications

- Industrial Inverter
- Uninterruptible Power Supply
- Induction Heating
- Isolated IGBT/Power MOSFET Gate Drive

Functional Block Diagram



Note:

1. 0.1 μ F bypass capacitor must be connected between pins 5 and 8.

Description

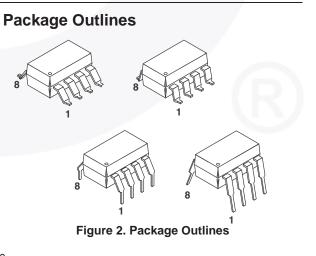
The FOD3120 is a 2.5 A Output Current Gate Drive Optocoupler, capable of driving most medium power IGBT/MOSFET. It is ideally suited for fast switching driving of power IGBT and MOSFETs used in motor control inverter applications, and high performance power system.

It utilizes Fairchild's coplanar packaging technology, Optoplanar[®], and optimized IC design to achieve high noise immunity, characterized by high common mode rejection.

It consists of a gallium aluminum arsenide (AlGaAs) light emitting diode optically coupled to an integrated circuit with a high-speed driver for push-pull MOSFET output stage.

Related Resources

- FOD3150, 1 A Output Current, Gate Drive Optocoupler Datasheet
- www.fairchildsemi.com/products/optoelectronics/



Truth Table

| LED | V _{DD} -V _{SS} "Positive Going" (Turn-on) | V _{DD} -V _{SS} "Negative Going" (Turn-off) | v _o |
|-----|--|---|----------------|
| Off | 0 V to 30 V | 0 V to 30 V | Low |
| On | 0 V to 11.5 V | 0 V to 10 V | Low |
| On | 11.5 V to 13.5 V | 10 V to 12 V | Transition |
| On | 13.5 V to 30 V | 12 V to 30 V | High |

Pin Definitions

| Pin # | Name | Description |
|-------|-----------------|---|
| 1 | NC | Not Connected |
| 2 | Anode | LED Anode |
| 3 | Cathode | LED Cathode |
| 4 | NC | Not Connected |
| 5 | V _{SS} | Negative Supply Voltage |
| 6 | V _{O2} | Output Voltage 2 (internally connected to V _{O1}) |
| 7 | V _{O1} | Output Voltage 1 |
| 8 | V _{DD} | Positive Supply Voltage |

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|--|--|
| OD3120 Rev. 1.4 | |

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Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter | Characteristics | |
|--|--|-----------|
| | < 150 V _{RMS} | I–IV |
| Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage | < 300 V _{RMS} | I–IV |
| | < 450 V _{RMS} | I–III |
| | < 600 V _{RMS} | I–III |
| | < 1000 V _{RMS} (Option T, TS) | I–III |
| Climatic Classification | | 40/100/21 |
| Pollution Degree (DIN VDE 0110/1.89) | | 2 |
| Comparative Tracking Index | | 175 |

| Symbol | Parameter | Value | Unit |
|-----------------------|---|-------------------|-------------------|
| M | Input-to-Output Test Voltage, Method A, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with $t_m = 10$ s, Partial Discharge < 5 pC | 2,262 | V _{peak} |
| V _{PR} | Input-to-Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with $t_m = 1 \text{ s}$, Partial Discharge < 5 pC | 2,651 | V _{peak} |
| VIORM | Maximum Working Insulation Voltage | 1,414 | V _{peak} |
| V _{IOTM} | Highest Allowable Over-Voltage | 6,000 | V _{peak} |
| | External Creepage | ≥ 8.0 | mm |
| | External Clearance | ≥ 7.4 | mm |
| | External Clearance (for Option T or TS, 0.4" Lead Spacing) | ≥ 10.16 | mm |
| DTI | Distance Through Insulation (Insulation Thickness) | ≥ 0.5 | mm |
| Τ _S | Case Temperature ⁽²⁾ | 175 | °C |
| I _{S,INPUT} | Input Current ⁽²⁾ | 400 | mA |
| P _{S,OUTPUT} | Output Power (Duty Factor $\leq 2.7\%$) ⁽²⁾ | 700 | mW |
| R _{IO} | Insulation Resistance at T_S , V_{IO} = 500 $V^{(2)}$ | > 10 ⁹ | Ω |

Note:

2. Safety limit value - maximum values allowed in the event of a failure.

Absolute Maximum Ratings (T_A = 25°C unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Paramete | er | Value | Unit |
|---|---|-----------------------|----------------------|------|
| T _{STG} | Storage Temperature | | -55 to +125 | °C |
| T _{OPR} | Operating Temperature | | -40 to +100 | °C |
| TJ | Junction Temperature | | -40 to +125 | °C |
| T _{SOL} | Lead Wave Solder Temperature (refer to page 21 for reflow solder | profile) | 260 for 10sec | °C |
| I _{F(AVG)} | Average Input Current | | 25 | mA |
| I _{F(PEAK)} | Peak Transient Forward Current ⁽³ | 3) | 1 | А |
| f | Operating Frequency ⁽⁴⁾ | | 50 | kHz |
| V _R | Reverse Input Voltage | | 5 | V |
| I _{O(PEAK)} | Peak Output Current ⁽⁵⁾ | | 3.0 | А |
| | Supply Voltage | | 0 to 35 | V |
| $V_{DD} - V_{SS}$ | Supply Voltage | $T_A \ge 90^{\circ}C$ | 0 to 30 | v |
| V _{O(PEAK)} | Peak Output Voltage | | 0 to V _{DD} | V |
| t _{R(IN)} , t _{F(IN)} | Input Signal Rise and Fall Time | | 500 | ns |
| PDI | Input Power Dissipation ⁽⁶⁾⁽⁸⁾ | | 45 | mW |
| PD _O | Output Power Dissipation ⁽⁷⁾⁽⁸⁾ | | 250 | mW |

Notes:

3. Pulse Width, $P_W \leq 1~\mu s,\,300~pps$

- 4. Exponential Waveform, $I_{O(PEAK)} \le | 2.5 \text{ A} | (\le 0.3 \text{ } \mu\text{s})$
- 5. Maximum pulse width = 10 µs, maximum duty cycle = 1.1%
- 6. Derate linearly above 87°C, free air temperature at a rate of 0.77 mW/°C
- 7. No derating required across temperature range.
- 8. Functional operation under these conditions is not implied. Permanent damage may occur if the device is subjected to conditions outside these ratings.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter | Value | Unit |
|---------------------|-------------------------------|-------------|------|
| T _A | Ambient Operating Temperature | -40 to +100 | °C |
| $V_{DD} - V_{SS}$ | Power Supply | 15 to 30 | V |
| I _{F(ON)} | Input Current (ON) | 7 to 16 | mA |
| V _{F(OFF)} | Input Voltage (OFF) | 0 to 0.8 | V |

Isolation Characteristics

Apply over all recommended conditions, typical value is measured at $T_A = 25^{\circ}C$

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|------------------|-----------------------------------|--|-------|------------------|------|------------------|
| V _{ISO} | Input-Output Isolation Voltage | $ \begin{array}{l} T_{A} = 25^{\circ}C, \ R.H. < 50\%, \ t = 1.0min, \\ I_{I-O} \leq 10 \ \mu A, \ 50 \ Hz^{(9)(10)} \end{array} $ | 5,000 | | | V _{RMS} |
| R _{ISO} | Isolation Resistance | $V_{I-O} = 500 V^{(9)}$ | | 10 ¹¹ | | Ω |
| C _{ISO} | Isolation Capacitance | $V_{I-O} = 0 V$, Freq = 1.0 MHz ⁽⁹⁾ | | 1 | | pF |

Notes:

9. Device is considered a two terminal device: Pins 2 and 3 are shorted together and Pins 5, 6, 7 and 8 are shorted together.

10. 5,000 V_{RMS} for 1 minute duration is equivalent to 6,000 VAC_{RMS} for 1 second duration.

Electrical Characteristics

Apply over all recommended conditions, typical value is measured at V_{DD} = 30 V, V_{SS} = Ground, T_A = 25°C unless otherwise specified.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit | |
|-------------------------|---|---|--------------------------|-------------------------|--------------------------|-------|--|
| V _F | Input Forward Voltage | I _F = 10 mA | 1.2 | 1.5 | 1.8 | V | |
| $\Delta(V_{F} / T_{A})$ | Temperature Coefficient of Forward Voltage | | | -1.8 | | mV/ºC | |
| BV _R | Input Reverse Breakdown Voltage | I _R = 10 μA | 5 | | | V | |
| C _{IN} | Input Capacitance | f = 1 MHz, V _F = 0V | | 60 | | pF | |
| 1 | High Level Output | V _O = V _{DD} – 3 V | -1.0 | -2.0 | -2.5 | А | |
| I _{OH} | Current ⁽⁴⁾ | $V_{O} = V_{DD} - 6 V$ | -2.0 | | -2.5 | | |
| | Low Level Output | V _O = V _{SS} + 3 V | 1.0 | 2.0 | 2.5 | А | |
| I _{OL} | Current ⁽⁴⁾ | $V_{O} = V_{SS} + 6 V$ | 2.0 | | 2.5 | | |
| M | High Level Output Voltage | I _F = 10 mA, I _O = -2.5 A | V _{DD} – 6.25 V | $V_{DD} - 2.5 V$ | | v | |
| V _{OH} | | I _F = 10 mA, I _O = -100 mA | $V_{DD} - 0.25 V$ | V _{DD} – 0.1 V | | v | |
| M | Low Level Output Voltage | I _F = 0 mA, I _O = 2.5 A | | V _{SS} + 2.5 V | V _{SS} + 6.25 V | v | |
| V _{OL} | | I _F = 0 mA, I _O = 100 mA | | V_{SS} + 0.1 V | V_{SS} + 0.25 V | V | |
| I _{DDH} | High Level Supply Current | V _O = Open, I _F = 7 to 16 mA | | 2.8 | 3.8 | mA | |
| I _{DDL} | Low Level Supply Current | V _O = Open, V _F = 0 to 0.8 V | | 2.8 | 3.8 | mA | |
| I _{FLH} | Threshold Input Current Low to High | I _O = 0 mA, V _O > 5 V | | 2.3 | 5.0 | mA | |
| V _{FHL} | Threshold Input Voltage High to Low | I _O = 0 mA, V _O < 5 V | 0.8 | | | V | |
| V _{UVLO+} | Under Voltage Lockout | I _F = 10 mA, V _O > 5 V | 11.5 | 12.7 | 13.5 | V | |
| V _{UVLO} | Threshold | I _F = 10 mA, V _O < 5 V | 10.0 | 11.2 | 12.0 | V | |
| UVLO _{HYS} | Under Voltage Lockout Threshold Hysteresis | | | 1.5 | | V | |

Switching Characteristics

Apply over all recommended conditions, typical value is measured at V_{DD} = 30 V, V_{SS} = Ground, T_A = 25°C unless otherwise specified.

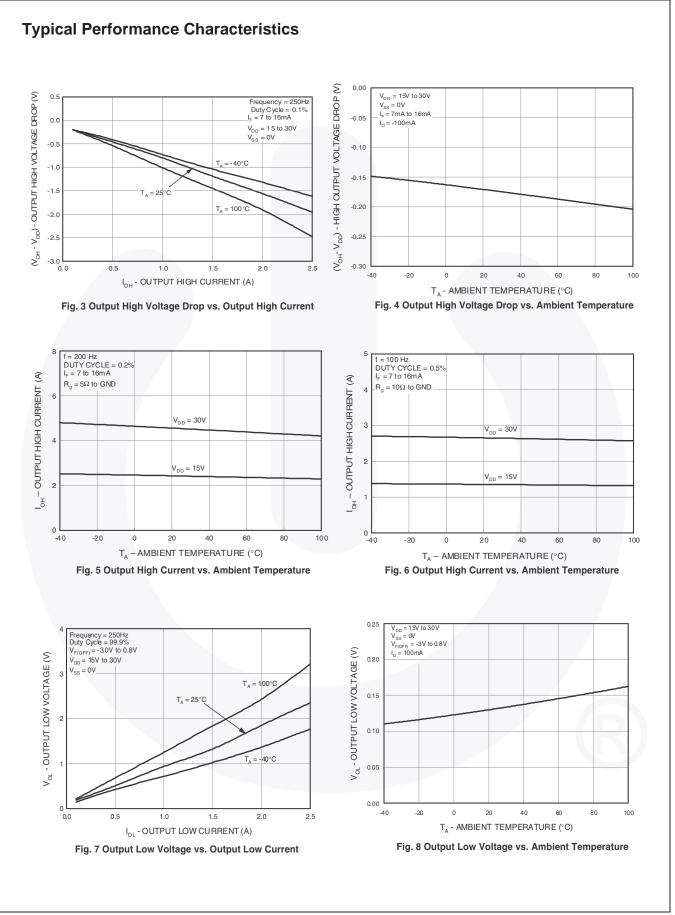
| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-----------------------|--|---|------|------|------|-------|
| t _{PHL} | Propagation Delay Time to Logic Low Output | | 150 | 275 | 400 | ns |
| t _{PLH} | Propagation Delay Time to Logic High Output | | 150 | 255 | 400 | ns |
| PWD | Pulse Width Distortion, t _{PHL} – t _{PLH} | I _F = 7 mA to 16 mA, Rg = 10 Ω , Cg =10 nF, | | 20 | 100 | ns |
| PDD (Skew) | Propagation Delay Difference Between Any Two Parts or Channels, $(t_{PHL} - t_{PLH})^{(11)}$ | f = 10 kHz, Duty Cycle = 50% | -250 | | 250 | ns |
| t _R | Output Rise Time (10% – 90%) | | | 60 | | ns |
| t _F | Output Fall Time (90% – 10%) | | | 60 | | ns |
| t _{UVLO ON} | UVLO Turn On Delay | I _F = 10 mA, V _O > 5 V | | 1.6 | | μs |
| t _{UVLO OFF} | UVLO Turn Off Delay | I _F = 10 mA, V _O < 5 V | | 0.4 | | μs |
| CM _H | Common Mode Transient Immunity at Output High | $T_A = 25^{\circ}C, V_{DD} = 30 V,$ $I_F = 7 \text{ to } 16 \text{ mA},$ $V_{CM} = 2000 V^{(12)}$ | 35 | 50 | | kV/µs |
| CM _L | Common Mode Transient Immunity at Output Low | $T_A = 25^{\circ}C, V_{DD} = 30 V, V_F = 0 V,$ $V_{CM} = 2000 V^{(13)}$ | 35 | 50 | | kV/µs |

Notes:

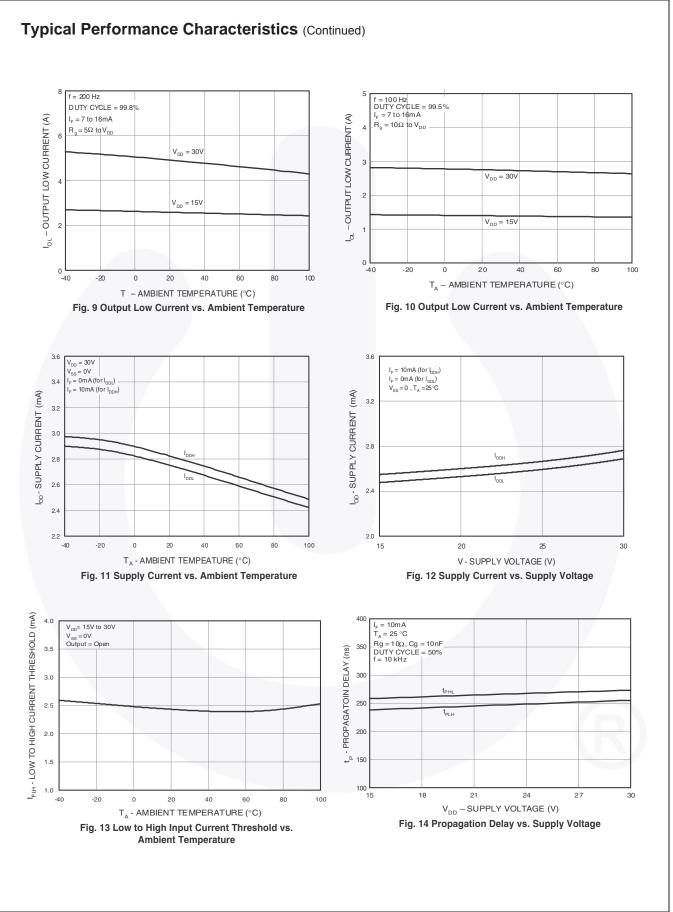
11. The difference between t_{PHL} and t_{PLH} between any two FOD3120 parts under same test conditions.

 Common mode transient immunity at output high is the maximum tolerable negative dVcm/dt on the trailing edge of the common mode impulse signal, Vcm, to assure that the output will remain high (i.e. V_O > 15.0 V).

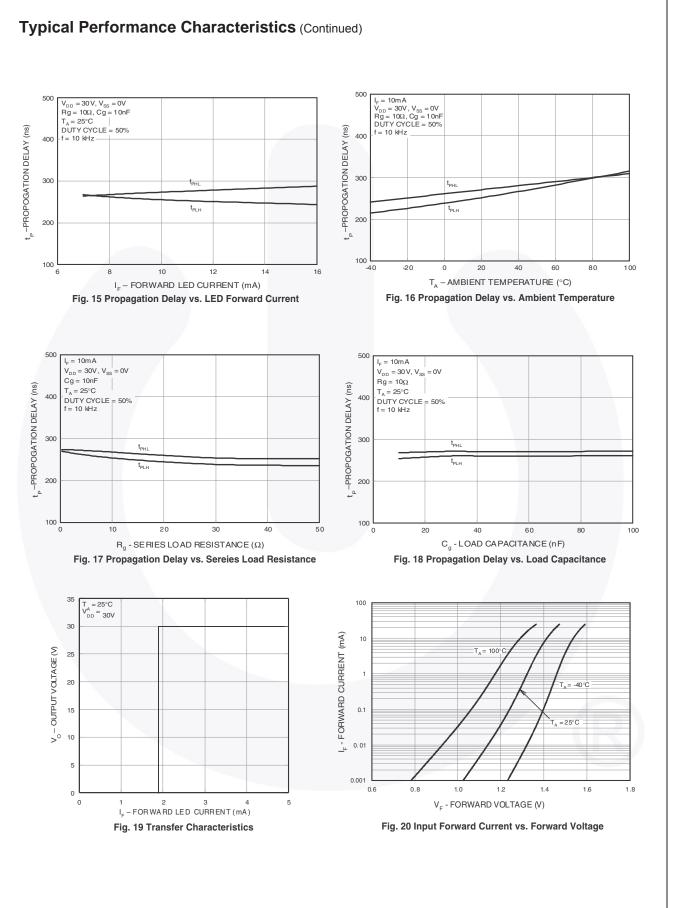
 Common mode transient immunity at output low is the maximum tolerable positive dVcm/dt on the leading edge of the common pulse signal, Vcm, to assure that the output will remain low (i.e. V_O < 1.0 V).

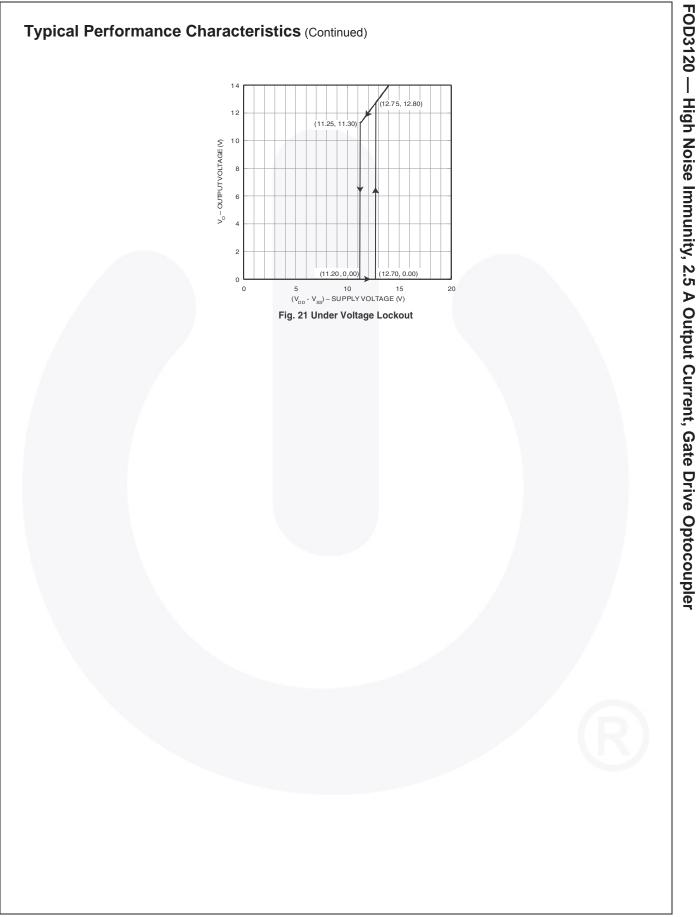


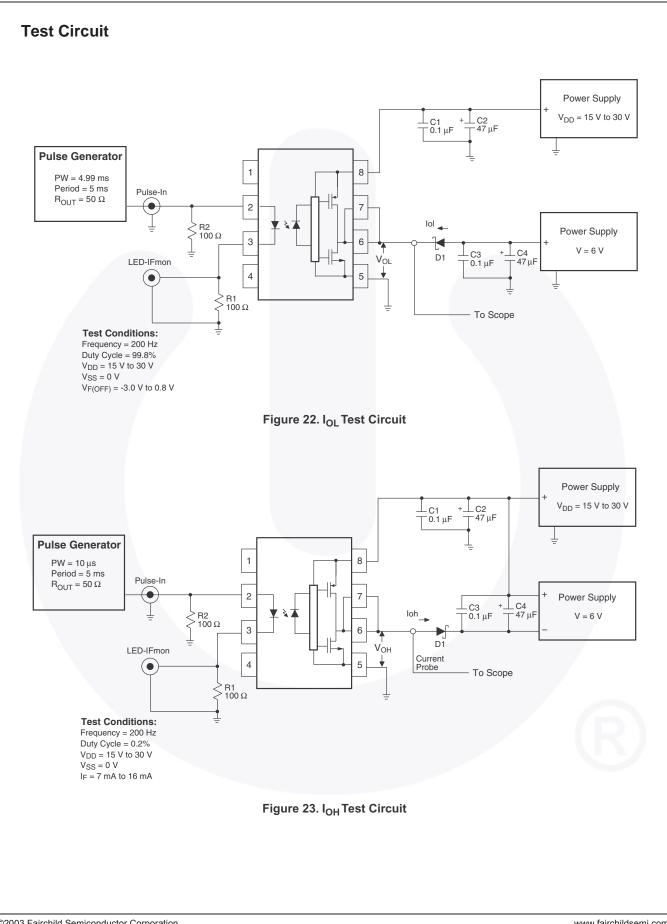
FOD3120 — High Noise Immunity, 2.5 A Output Current, Gate Drive Optocoupler



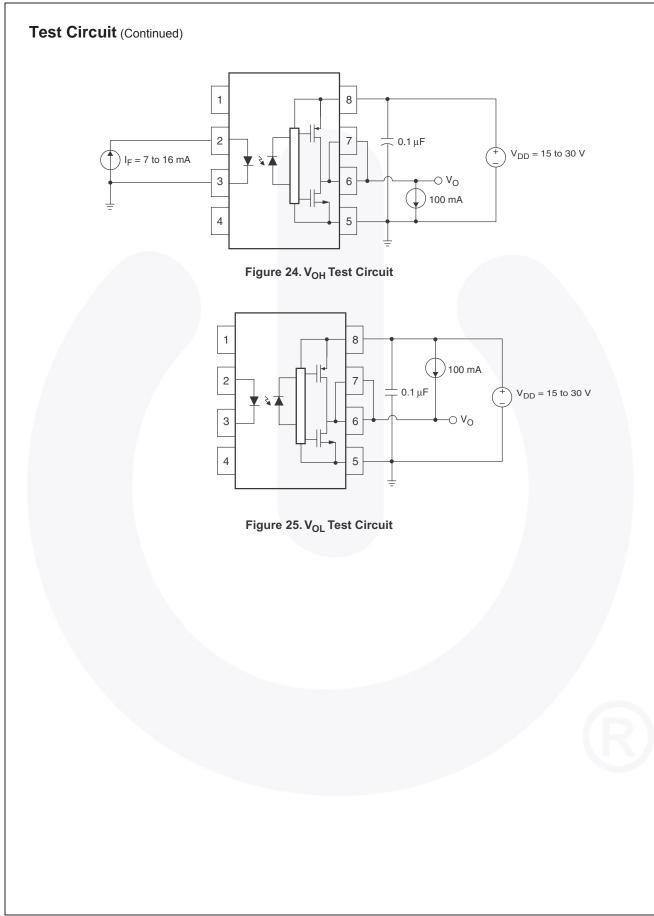
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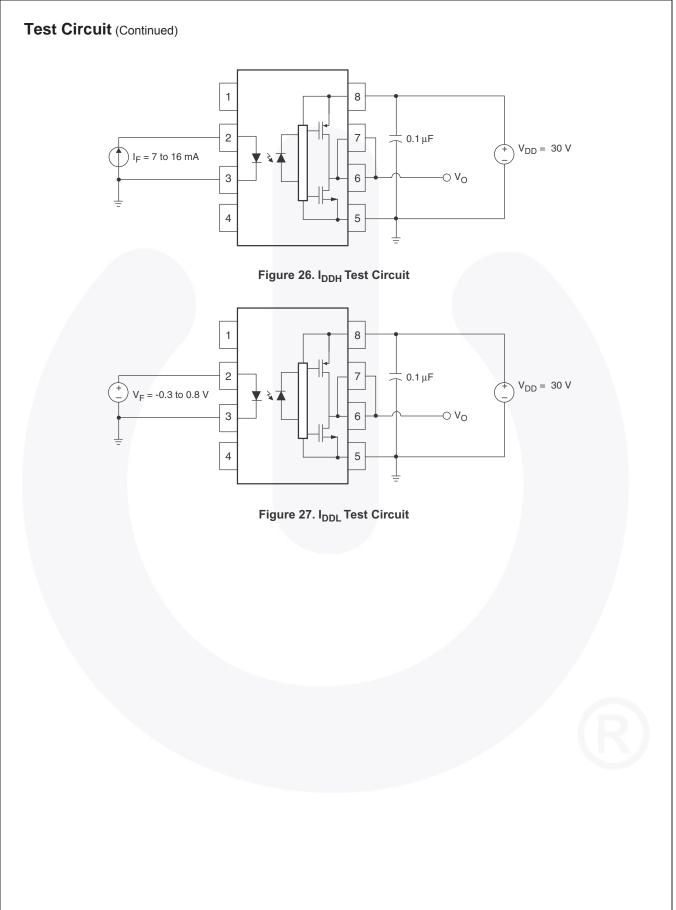




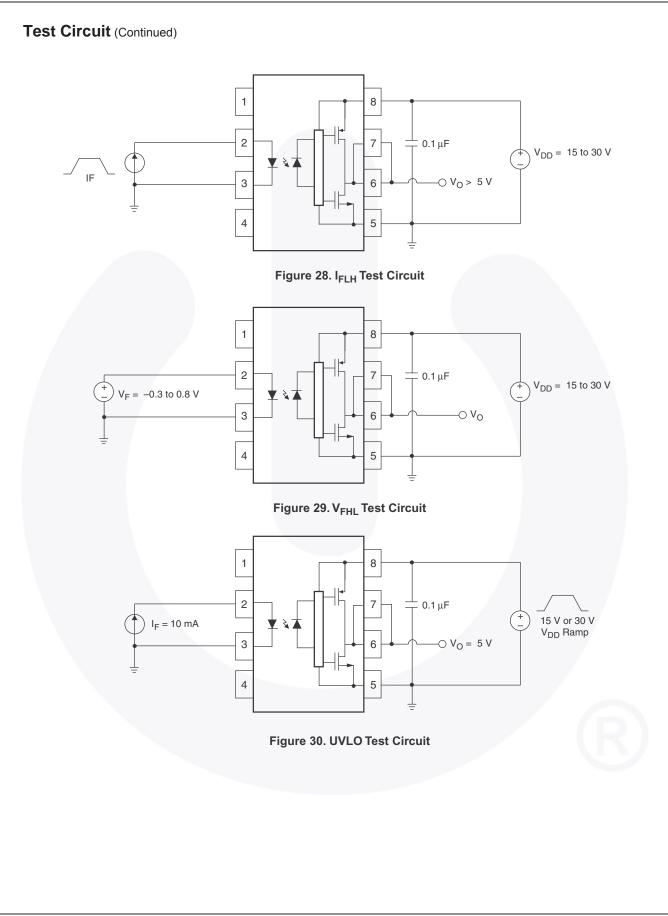


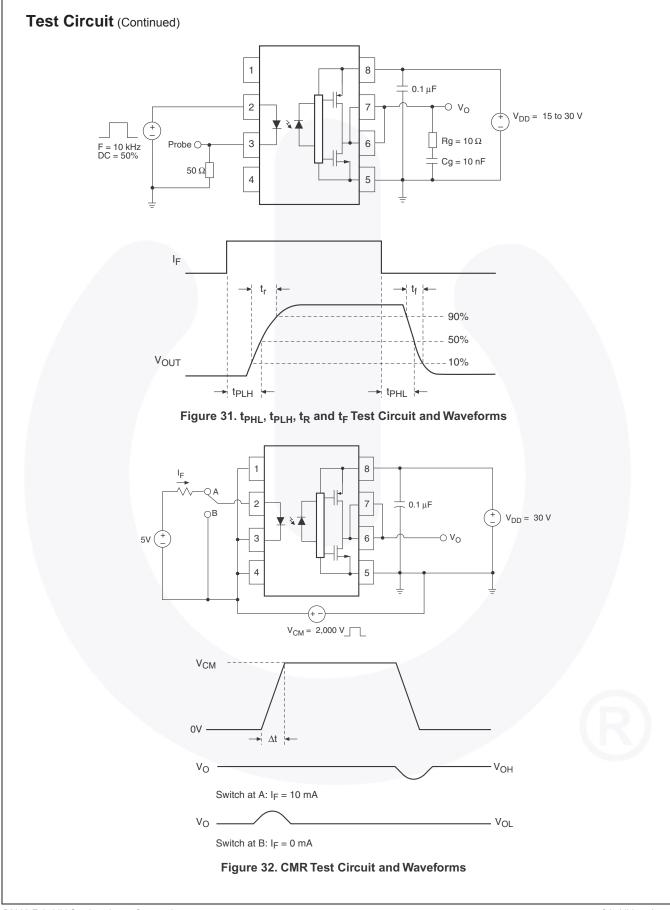
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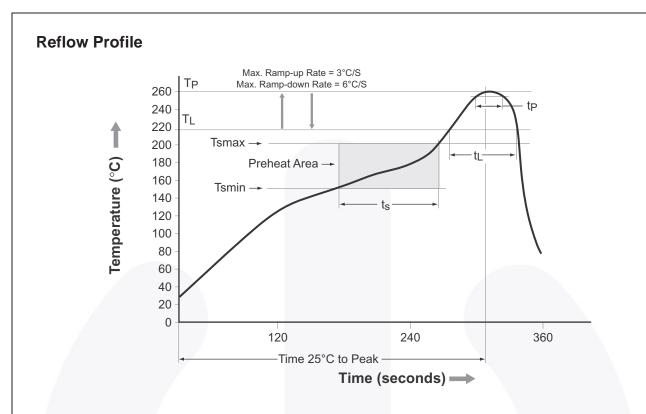




FOD3120 — High Noise Immunity, 2.5 A Output Current, Gate Drive Optocoupler







| Profile Freature | Pb-Free Assembly Profile | | |
|---|--------------------------|--|--|
| Temperature Min. (Tsmin) | 150°C | | |
| Temperature Max. (Tsmax) | 200°C | | |
| Time (t _S) from (Tsmin to Tsmax) | 60–120 seconds | | |
| Ramp-up Rate (t _L to t _P) | 3°C/second max. | | |
| Liquidous Temperature (T _L) | 217°C | | |
| Time (t _L) Maintained Above (T _L) | 60–150 seconds | | |
| Peak Body Package Temperature | 260°C +0°C / –5°C | | |
| Time (t _P) within 5°C of 260°C | 30 seconds | | |
| Ramp-down Rate (T _P to T _L) | 6°C/second max. | | |
| Time 25°C to Peak Temperature | 8 minutes max. | | |

Ordering Information

| Part Number | Package | Packing Method |
|--------------|--|--------------------------------------|
| FOD3120 | DIP 8-Pin | Tube (50 units per tube) |
| FOD3120S | SMT 8-Pin (Lead Bend) | Tube (50 units per tube) |
| FOD3120SD | SMT 8-Pin (Lead Bend) | Tape and Reel (1,000 units per reel) |
| FOD3120V | DIP 8-Pin, DIN_EN/IEC60747-5-5 option | Tube (50 units per tube) |
| FOD3120SV | SMT 8-Pin (Lead Bend), DIN_EN/IEC60747-5-5 option | Tube (50 units per tube) |
| FOD3120SDV | SMT 8-Pin (Lead Bend), DIN_EN/IEC60747-5-5 option | Tape and Reel (1,000 units per reel) |
| FOD3120TV | DIP 8-Pin, 0.4" Lead Spacing, DIN_EN/IEC60747-5-5 option | Tube (50 units per tube) |
| FOD3120TSV | SMT 8-Pin, 0.4" Lead Spacing, DIN_EN/IEC60747-5-5 option | Tube (50 units per tube) |
| FOD3120TSR2V | SMT 8-Pin, 0.4" Lead Spacing, DIN_EN/IEC60747-5-5 option | Tape and Reel (700 units per reel) |

Marking Information

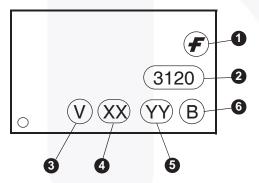
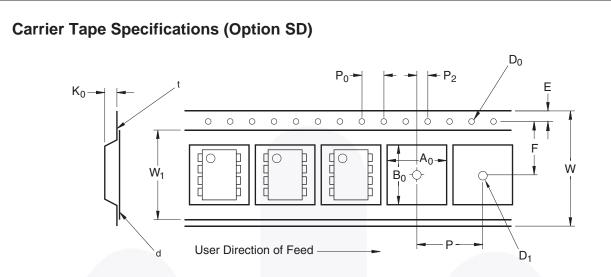
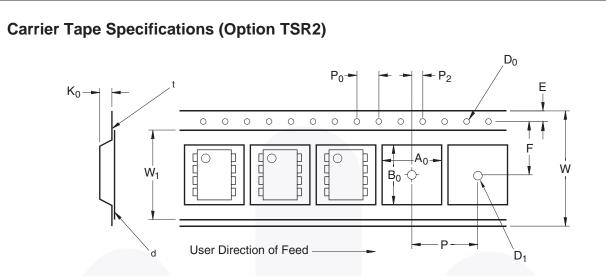


Figure 33. Top Mark

| Definitions | | | |
|-------------|--|--|--|
| 1 | Fairchild logo | | |
| 2 | Device number | | |
| 3 | DIN_EN/IEC60747-5-5 Option (only appears on component ordered with this option) | | |
| 4 | Two digit year code, e.g., '16' | | |
| 5 | Two digit work week ranging from '01' to '53' | | |
| 6 | Assembly package code | | |

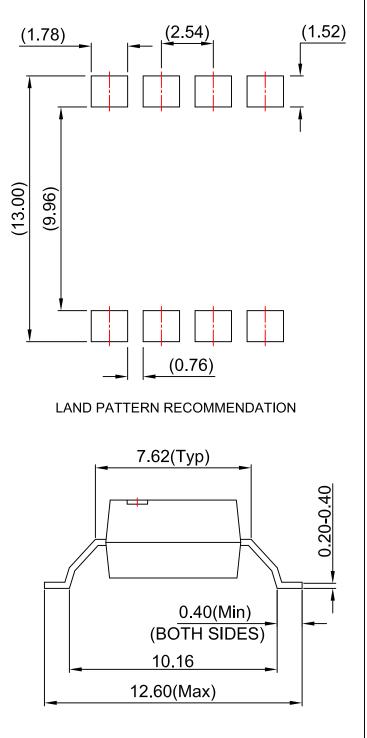


| Symbol | Description | Dimension in mm |
|----------------|---------------------------------|-----------------|
| W | Tape Width | 16.0 ± 0.3 |
| t | Tape Thickness | 0.30 ± 0.05 |
| P ₀ | Sprocket Hole Pitch | 4.0 ± 0.1 |
| D ₀ | Sprocket Hole Diameter | 1.55 ± 0.05 |
| E | Sprocket Hole Location | 1.75 ± 0.10 |
| F | Pocket Location | 7.5 ± 0.1 |
| P ₂ | | 2.0 ± 0.1 |
| Р | Pocket Pitch | 12.0 ± 0.1 |
| A ₀ | Pocket Dimensions | 10.30 ±0.20 |
| B ₀ | | 10.30 ±0.20 |
| K ₀ | | 4.90 ±0.20 |
| W ₁ | Cover Tape Width | 13.2 ± 0.2 |
| d | Cover Tape Thickness | 0.1 max |
| | Max. Component Rotation or Tilt | 10° |
| R | Min. Bending Radius | 30 |



| Symbol | Description | Dimension in mm | |
|----------------|---------------------------------|-----------------|--|
| W | Tape Width | 24.0 ± 0.3 | |
| t | Tape Thickness | 0.40 ± 0.1 | |
| P ₀ | Sprocket Hole Pitch | 4.0 ± 0.1 | |
| D ₀ | Sprocket Hole Diameter | 1.55 ± 0.05 | |
| E | Sprocket Hole Location | 1.75 ± 0.10 | |
| F | Pocket Location | 11.5 ± 0.1 | |
| P ₂ | | 2.0 ± 0.1 | |
| Р | Pocket Pitch | 16.0 ± 0.1 | |
| A ₀ | Pocket Dimensions | 12.80 ± 0.1 | |
| B ₀ | | 10.35 ± 0.1 | |
| K ₀ | | 5.7 ±0.1 | |
| W ₁ | Cover Tape Width | 21.0 ± 0.1 | |
| d | Cover Tape Thickness | 0.1 max | |
| | Max. Component Rotation or Tilt | 10° | |
| R | Min. Bending Radius | 30 | |

1.500 4 <u>Ø1.00</u> (TYP) 6 35-6 86 5 8 9.40-9.91 1.14-1.78 3.68-3.94 5.08 Max



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NOTES:

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A) NO STANDARD APPLIES TO THIS PACKAGE

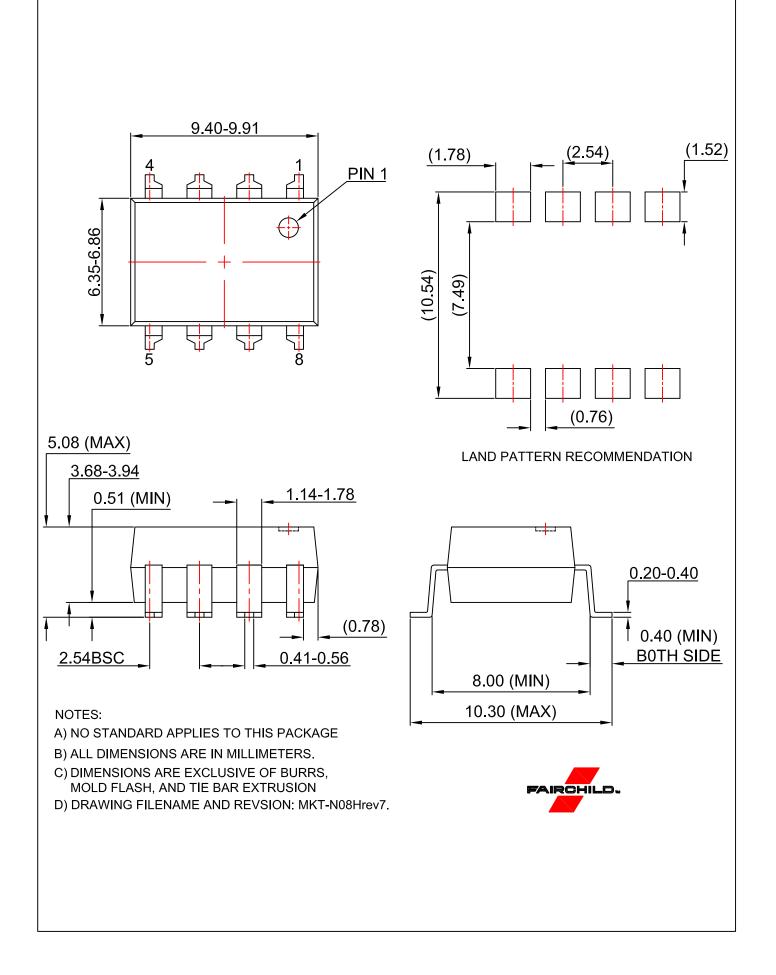
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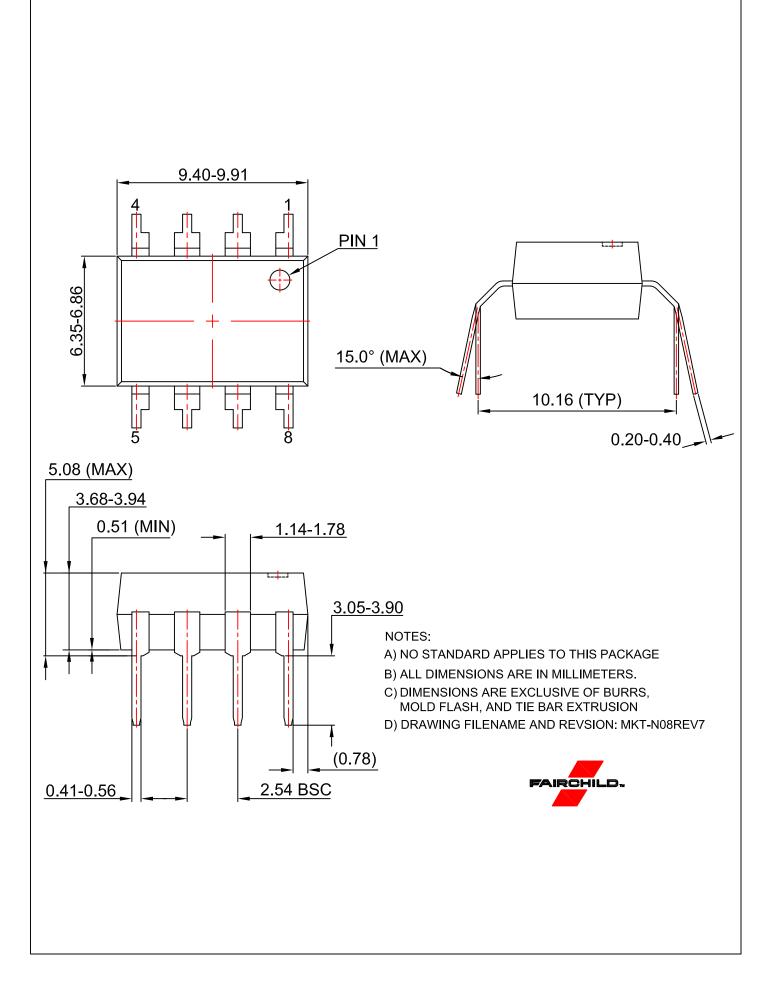
0.510(Min)

B) ALL DIMENSIONS ARE IN MILLIMETERS.

C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIOND) DWG FILENAME AND REVISION: MKT-N08Lrev2.









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Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

| Definition of Terms | | | | | |
|--------------------------|-----------------------|---|--|--|--|
| Datasheet Identification | Product Status | Definition | | | |
| Advance Information | Formative / In Design | Datasheet contains the design specifications for product development. Specifications may change in any manner without notice. | | | |
| Preliminary | First Production | Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. | | | |
| No Identification Needed | Full Production | Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design. | | | |
| Obsolete | Not In Production | Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only. | | | |

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Mouser Electronics

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